Product data sheet

HEF4520B-Q100

Dual binary counter Rev. 1 — 14 March 2017

1 General description

The HEF4520B-Q100 is a dual 4-bit internally synchronous binary counter. The counter has an active HIGH clock input (nCP0) and an active LOW clock input (n $\overline{CP1}$), buffered outputs from all four bit positions (nQ0 to nQ3) and an active HIGH overriding asynchronous master reset input (nMR).

The counter advances on either the LOW-to-HIGH transition of the nCP0 input if $n\overline{CP1}$ is HIGH or the HIGH-to-LOW transition of the $n\overline{CP1}$ input if nCP0 is LOW. Either nCP0 or $n\overline{CP1}$ may be used as the clock input to the counter while the other clock input may be used as a clock enable input. Schmitt trigger action makes the clock input highly tolerant of slower clock rise and fall times. A HIGH on nMR resets the counter (nQ0 to nQ3 = LOW) independent of nCP0 and $n\overline{CP1}$.

It operates over a recommended V_{DD} power supply range of 3 V to 15 V referenced to V_{SS} (usually ground). Unused inputs must be connected to V_{DD} , V_{SS} , or another input.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 3) and is suitable for use in automotive applications.

2 Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 3)
 Specified from -40 °C to +85 °C
- · Tolerant of slow clock rise and fall times
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- ESD protection:
 - MIL-STD-883, method 3015 exceeds 2000 V
 - HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Complies with JEDEC standard JESD 13-B

3 Ordering information

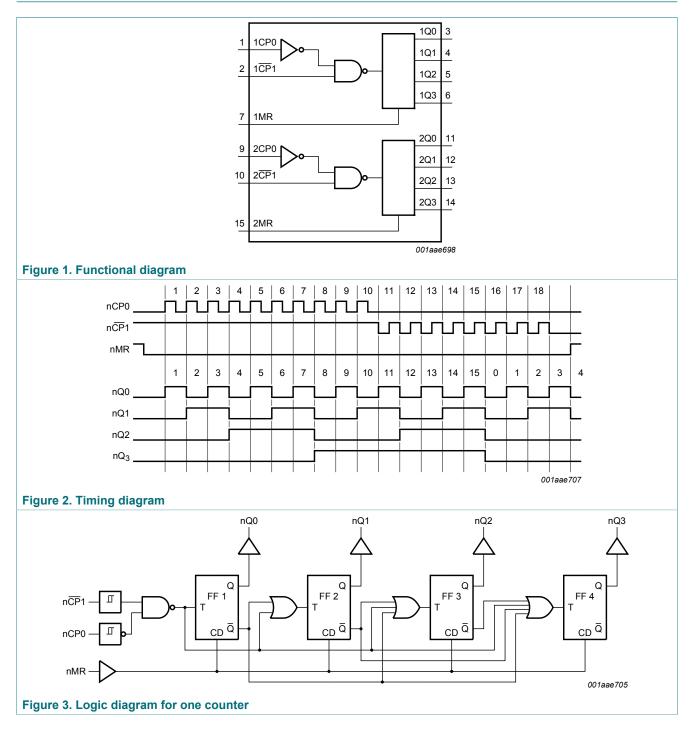
Table 1. Ordering information

All types operate from -40 °C to +85 °C.

Type number	Package					
	Name	Description	Version			
HEF4520BT-Q100	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1			

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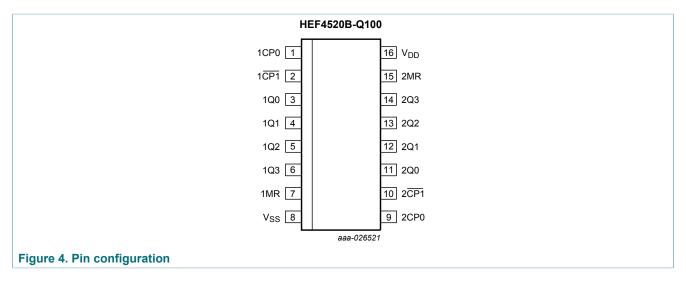
4 Functional diagram



Dual binary counter

5 Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1CP0, 2CP0	1, 9	clock input (LOW-to-HIGH triggered)
1CP1, 2CP1	2, 10	clock input (HIGH-to-LOW triggered)
1Q0 to 1Q3	3, 4, 5, 6	output
1MR, 2MR	7, 15	master reset input
V _{SS}	8	ground supply voltage
2Q0 to 2Q3	11, 12, 13, 14	output
V _{DD}	16	supply voltage

6 Functional description

Table 3. Fun	ction tal	ble ^[1]	
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nCP0	nCP1	nMR	Mode
1	Н	L	counter advances
L	Ļ	L	counter advances
\downarrow	Х	L	no change
Х	1	L	no change
1	L	L	no change
Н	Ļ	L	no change
Х	X	Н	nQ0 to nQ3 = LOW

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; \uparrow = positive-going transition; \downarrow = negative-going transition.

7 Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to VSS = 0 V (ground).

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{DD}	supply voltage		-0.5	+18	V
I _{IK}	input clamping current	V_{I} < -0.5 V or V_{I} > V_{DD} + 0.5 V	-	±10	mA
VI	input voltage		-0.5	V _{DD} + 0.5	V
I _{OK}	output clamping current	$V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm DD}$ + 0.5 V	-	±10	mA
I _{I/O}	input/output current		-	±10	mA
I _{DD}	supply current		-	50	mA
T _{stg}	storage temperature	per output	-65	+150	°C
T _{amb}	ambient temperature		-40	+85	°C
P _{tot}	total power dissipation	SO16 package ^[1]	-	500	mW
Р	power dissipation		-	100	mW

[1] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

8 Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DD}	supply voltage		3	-	15	V
VI	input voltage		0	-	V_{DD}	V
T _{amb}	ambient temperature	in free air	-40	-	+85	°C
Δt/ΔV	input transition rise and fall rate	V _{DD} = 5 V	-	-	3.75	µs/V
		V _{DD} = 10 V	-	-	0.5	μs/V
		V _{DD} = 15 V	-	-	0.08	μs/V

9 Static characteristics

Table 6. Static characteristics

 V_{SS} = 0 V; V_I = V_{SS} or V_{DD} unless otherwise specified.

Symbol	Parameter	Conditions	V _{DD}	T _{amb} = -40 °C		T _{amb} = 25 °C		T _{amb} = 85 °C		Unit
				Min	Мах	Min	Max	Min	Max	
V _{IH}	HIGH-level input	I _O < 1 μΑ	5 V	3.5	-	3.5	-	3.5	-	V
voltage	voltage		10 V	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	V
V _{IL}	LOW-level input	I _O < 1 μΑ	5 V	-	1.5	-	1.5	-	1.5	V
	voltage		10 V	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	V
V _{OH}	HIGH-level output	I _O < 1 μA;	5 V	4.95	-	4.95	-	4.95	-	V
	voltage	$V_{I} = V_{SS} \text{ or } V_{DD}$	10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	V
V _{OL}	LOW-level output voltage	$ I_O < 1 \ \mu A;$ V _I = V _{SS} or V _{DD}	5 V	-	0.05	-	0.05	-	0.05	V
			10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
I _{OH}	HIGH-level output	V _O = 2.5 V	5 V	-	-1.7	-	-1.4	-	-1.1	mA
	current	V _O = 4.6 V	5 V	-	-0.52	-	-0.44	-	-0.36	mA
		V _O = 9.5 V	10 V	-	-1.3	-	-1.1	-	-0.9	mA
		V _O = 13.5 V	15 V	-	-3.6	-	-3.0	-	-2.4	mA
I _{OL}	LOW-level output	V _O = 0.4 V	5 V	0.52	-	0.44	-	0.36	-	mA
	current	V _O = 0.5 V	10 V	1.3	-	1.1	-	0.9	-	mA
		V _O = 1.5 V	15 V	3.6	-	3.0	-	2.4	-	mA
l _l	input leakage current	V _{DD} = 15 V	15 V	-	±0.3	-	±0.3	-	±1.0	μA
I _{DD}	supply current	$I_{O} = 0 A;$	5 V	-	20	-	20	-	150	μA
		$V_{I} = V_{SS} \text{ or } V_{DD}$	10 V	-	40	-	40	-	300	μA
			15 V	-	80	-	80	-	600	μA
CI	input capacitance		-	-	-	-	7.5	-	-	pF

10 Dynamic characteristics

Table 7. Dynamic characteristics

 $V_{SS} = 0 V$; $T_{amb} = 25 °C$; for test circuit see Figure 6; unless otherwise specified.

Symbol	Parameter	Conditions	V _{DD}	Extrapolation formula	Min	Тур	Max	Unit
t _{PHL}	HIGH to LOW	nCP0, nCP1 to nQn;	5 V ^[1]	83 ns + (0.55 ns/pF)C _L	-	110	220	ns
	propagation delay	see <u>Figure 5</u>	10 V	39 ns + (0.23 ns/pF)C _L	-	50	100	ns
			15 V	32 ns + (0.16 ns/pF)C _L	-	40	80	ns
		nMR to nQn;	5 V	48 ns + (0.55 ns/pF)C _L	-	75	150	ns
		see <u>Figure 5</u>	10 V	24 ns + (0.23 ns/pF)C _L	-	35	70	ns
			15 V	17 ns + (0.16 ns/pF)C _L	-	25	50	ns
t _{PLH}	LOW to HIGH	nCP0, nCP1 to nQn;	5 V ^[1]	83 ns + (0.55 ns/pF)C _L	-	110	220	ns
	propagation delay	see <u>Figure 5</u>	10 V	39 ns + (0.23 ns/pF)C _L	-	50	100	ns
			15 V	32 ns + (0.16 ns/pF)C _L	-	40	80	ns
tt	transition time	nQn; see Figure 5	5 V ^[1]	10 ns + (1.00 ns/pF)C _L	-	60	120	ns
			10 V	9 ns + (0.42 ns/pF)C _L	-	30	60	ns
			15 V	6 ns + (0.28 ns/pF)C _L	-	20	40	ns
t _W pulse width	pulse width	nCP0 input LOW;	5 V		60	30	-	ns
		minimum width; see Figure 5	10 V		30	15	-	ns
			15 V		20	10	-	ns
		nCP1 input HIGH; minimum width; see <u>Figure 5</u>	5 V		60	30	-	ns
			10 V		30	15	-	ns
			15 V		20	10	-	ns
		nMR input HIGH; minimum width; see <u>Figure 5</u>	5 V		30	15	-	ns
			10 V		20	10	-	ns
			15 V		16	8	-	ns
t _{su}	set-up time	nCP0 to nCP1;	5 V		50	25	-	ns
		see <u>Figure 5</u>	10 V		30	15	-	ns
			15 V		20	10	-	ns
		nCP1 to nCP0;	5 V		50	25	-	ns
		see <u>Figure 5</u>	10 V		30	15	-	ns
			15 V		20	10	-	ns
t _{rec}	recovery time	see Figure 5	5 V		50	25	-	ns
			10 V		30	15	-	ns
			15 V		20	10	-	ns
f _{max}	maximum	nCP0, n CP 1;	5 V		8	16	_	MHz
	frequency	see <u>Figure 5</u>	10 V		15	30	_	MHz
			15 V		20	40	_	MHz

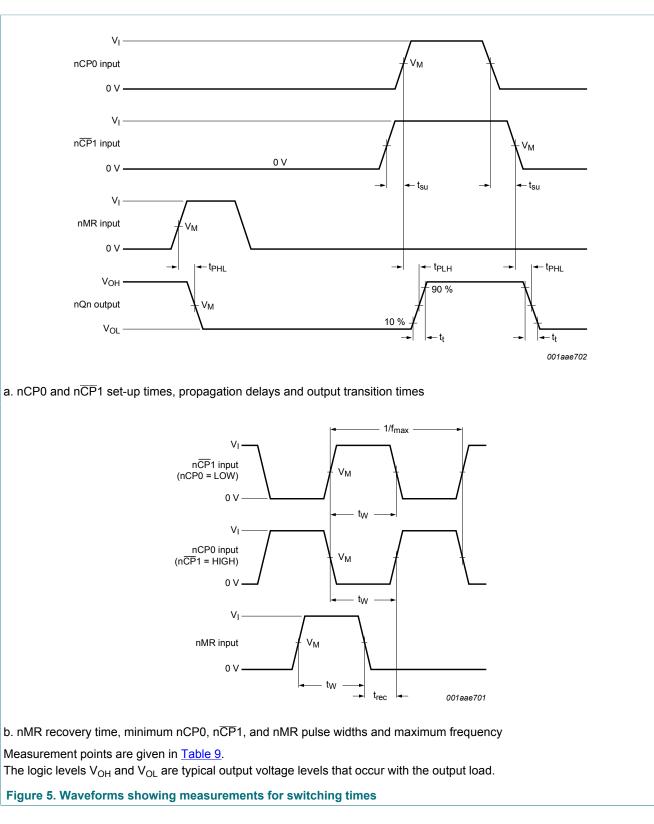
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[1] The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C_L in pF).

Table 8. Dynamic power dissipation P_D

 P_D can be calculated from the formulas shown. $V_{SS} = 0$ V; $t_r = t_f \le 20$ ns; $T_{amb} = 25$ °C.

Symbol	Parameter	V _{DD}	Typical formula for P_D (μ W)	Where:
P _D	dynamic power	5 V	$P_{D} = 850 \times f_{i} + \Sigma (f_{o} \times C_{L}) \times V_{DD}^{2}$	f_i = input frequency in MHz,
	dissipation	10 V		$f_o =$ output frequency in MHz, C _L = output load capacitance in pF,
		15 V	$D = 40000 \text{ wf} + \nabla (f + C + W) / f$	V_{DD} = supply voltage in V, $\Sigma(f_o \times C_L)$ = sum of the outputs.



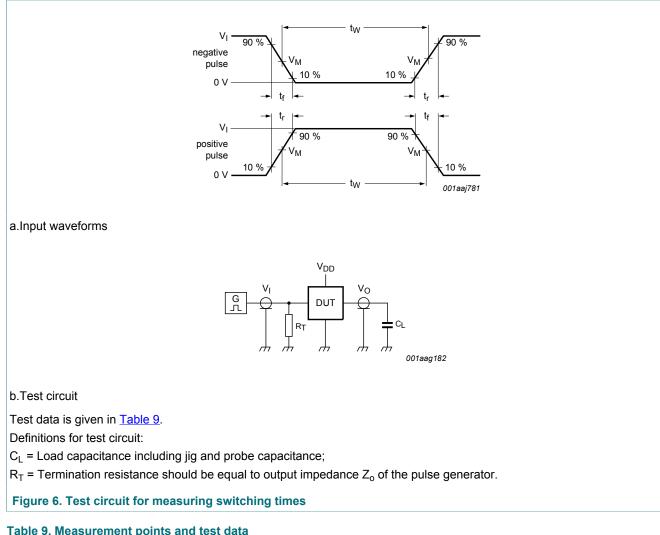
10.1 Waveforms and test circuit

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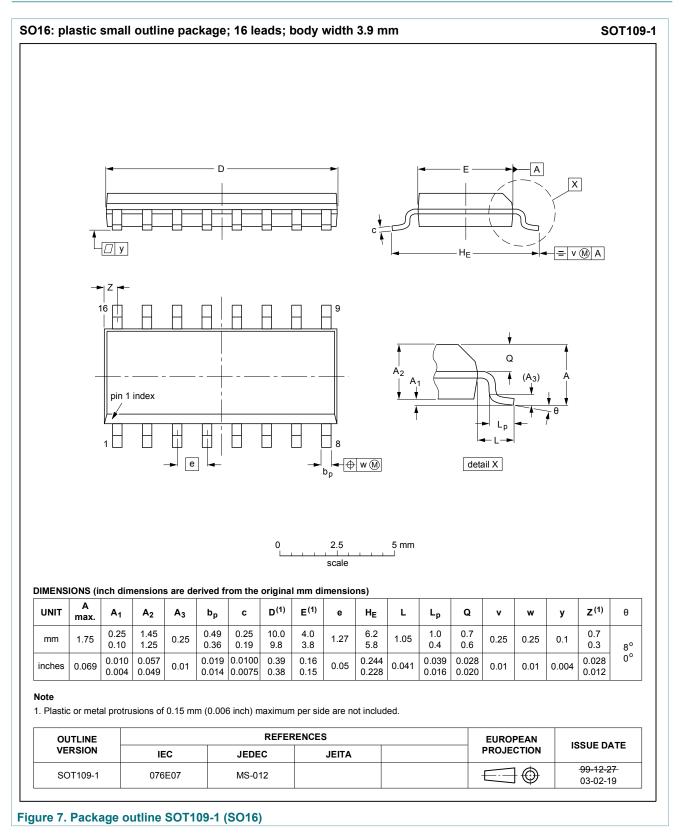
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Supply voltage	Input	Load		
V _{DD}	VI	V _M	t _r , t _f	CL
5 V to 15 V	V _{DD}	0.5V _I	≤ 20 ns	50 pF

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11 Package outline



Dual binary counter

12 Abbreviations

Table 10. Abbreviations					
Acronym	Description				
DUT	Device Under Test				
ESD	ElectroStatic Discharge				
НВМ	Human Body Model				
MIL	Military				
MM	Machine Model				

13 Revision history

Table 11. Revision history							
Document ID	Release date	Data sheet status	Change notice	Supersedes			
HEF4520B_Q100 v.1	20170314	Product data sheet	-	-			

14 Legal information

14.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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